1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a DSN0603-2 (SOD962-2) leadless ultra small Chip-Scale Package (CSP).

2. Features and benefits

- Average forward current I_{F(AV)} ≤ 0.2 A
- Reverse voltage V_R ≤ 30 V
- Low forward voltage typ. V_F = 250 mV
- Low reverse current typ. I_R = 4 μA
- Package height typ. 0.3 mm

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Ultra high speed switching
- LED backlight for mobile application

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; $T_{amb} \le$ 140 °C; square wave	[1]	-	-	0.2	А
		δ = 0.5; f = 20 kHz; $T_{sp} \le$ 147 °C; square wave		-	-	0.2	А
V _R	reverse voltage	T _j = 25 °C		-	-	30	V
V _F	forward voltage	I_F = 10 mA; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C		-	250	320	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C; pulsed		-	4	30	μA
t _{rr}	reverse recovery time	I_F = 500 mA; I_R = 500 mA; $I_{R(meas)}$ = 100 mA; T_j = 25 °C		-	1.37	-	ns

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al_2O_3 , standard footprint.





5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		1 - 1 - 2
2	Α	anode		sym001
			Transparent top view	
			DSN0603-2 (SOD962-2)	

^[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage					
	Name	Description	Version				
PMEG3002AESF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMEG3002AESF	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _R	reverse voltage	T _j = 25 °C		-	30	V
I _F	forward current	T _{sp} ≤ 145 °C; δ = 1		-	0.28	Α
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; $T_{amb} \le$ 140 °C; square wave	[1]	-	0.2	A
		δ = 0.5; f = 20 kHz; T _{sp} ≤ 147 °C; square wave		-	0.2	A
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.25$		-	1.5	Α
I _{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	4	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	405	mW
			[3]	-	660	mW
			[1]	-	1200	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient			[1][2]	-	-	310	K/W
			[1][3]	-	-	190	K/W
		[1][4]	-	-	105	K/W	
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[5]	-	-	40	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of anode tab.

PMEG3002AESF

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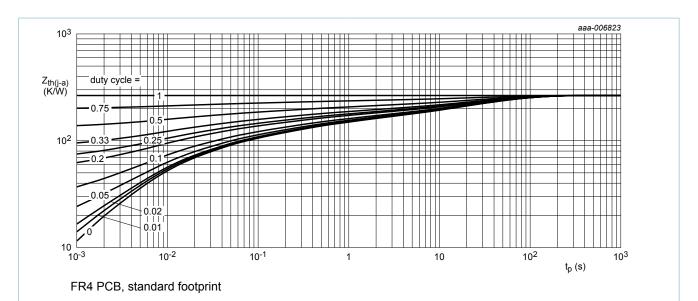


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

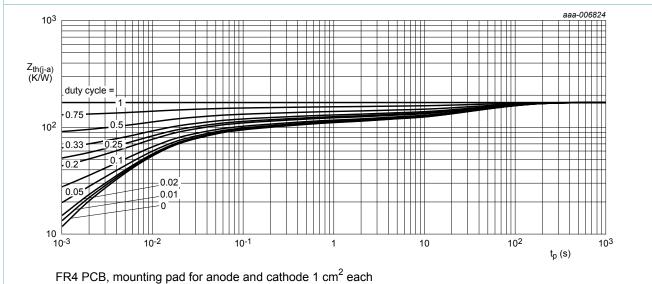
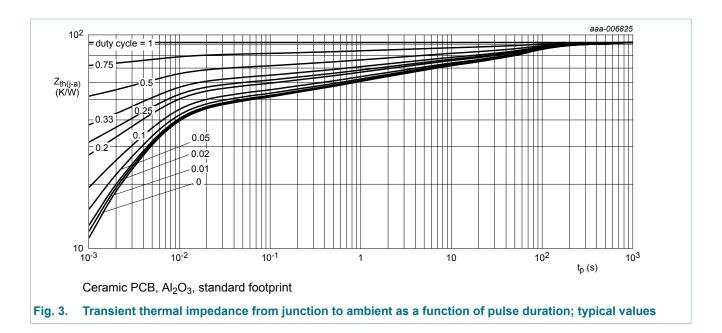


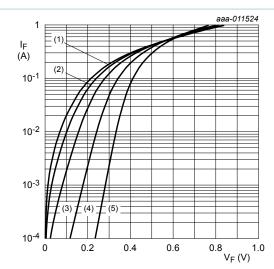
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)R}	reverse breakdown voltage	I_R = 100 μ A; t_p = 300 μ s; δ = 0.02; T_j = 25 °C	30	-	-	V
V _F forward voltage	forward voltage	I_F = 0.1 mA; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_j = 25 °C	-	120	185	mV
		I_F = 1 mA; $t_p \le 300$ μs; $δ \le 0.02$; T_j = 25 °C	-	180	245	mV
		I_F = 10 mA; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	250	320	mV
		I_F = 100 mA; $t_p \le$ 300 μ s; $\delta \le$ 0.02; T_j = 25 °C	-	350	410	mV
		I_F = 200 mA; $t_p \le 300$ μs; $δ \le 0.02$; T_j = 25 °C	-	405	470	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C; pulsed	-	4	30	μA
		V _R = 30 V; T _j = 25 °C; pulsed	-	20	80	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	22	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	8	-	pF
t _{rr}	reverse recovery time	I_F = 500 mA; I_R = 500 mA; $I_{R(meas)}$ = 100 mA; T_j = 25 °C	-	1.37	-	ns



pulsed condition

(1) $T_i = 150 \, ^{\circ}C$

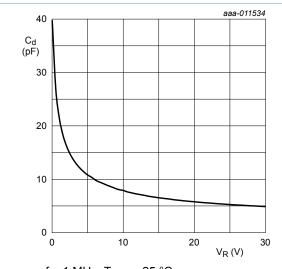
(2) $T_i = 125 \, ^{\circ}C$

(3) $T_j = 85 \, ^{\circ}C$

(4) $T_j = 25 \, ^{\circ}C$

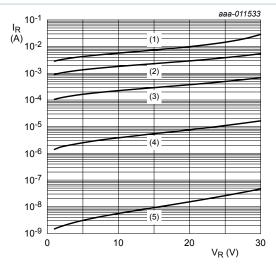
(5) $T_i = -40 \, ^{\circ}C$

Fig. 4. Forward current as a function of forward voltage; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$

Fig. 6. Diode capacitance as a function of reverse voltage; typical values



pulsed condition

(1) $T_i = 150 \, ^{\circ}C$

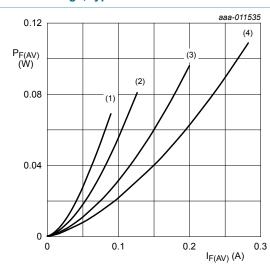
(2) $T_i = 125 \, ^{\circ}C$

(3) $T_j = 85 \, ^{\circ}C$

(4) $T_i = 25 \, ^{\circ}C$

(5) $T_i = -40 \, ^{\circ}\text{C}$

Fig. 5. Reverse current as a function of reverse voltage; typical values



 $T_i = 150 \,{}^{\circ}\text{C}$

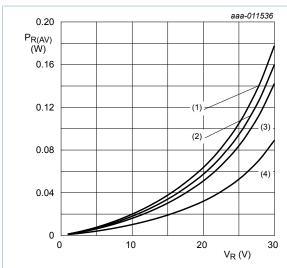
 $(1) \delta = 0.1$

 $(2) \delta = 0.2$

 $(3) \delta = 0.5$

 $(4) \delta = 1$

ig. 7. Average forward power dissipation as a function of average forward current; typical values



T_i = 125 °C

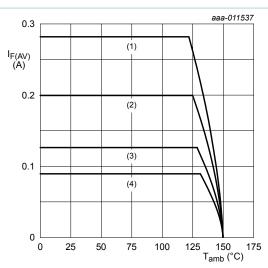
 $(1) \delta = 1$

 $(2) \delta = 0.9$

 $(3) \delta = 0.8$

 $(4) \delta = 0.5$

Average reverse power dissipation as a Fig. 8. function of reverse voltage; typical values



FR4 PCB, standard footprint

T_i = 150 °C

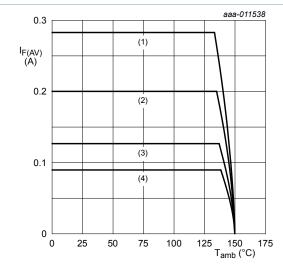
(1) δ = 1; DC

(2) $\delta = 0.5$; f = 20 kHz

(3) δ = 0.2; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig. 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for anode and cathode 1 cm² each

 $T_i = 150 \, ^{\circ}C$

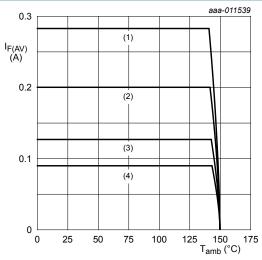
(1) δ = 1; DC

(2) $\delta = 0.5$; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al₂O₃, standard footprint

 $T_i = 150 \,{}^{\circ}\text{C}$

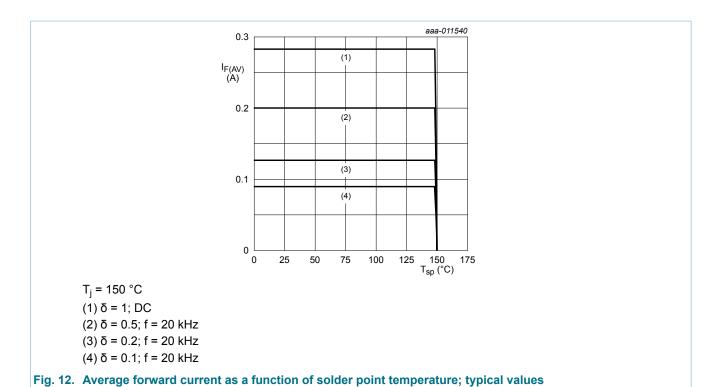
(1) δ = 1; DC

(2) δ = 0.5; f = 20 kHz

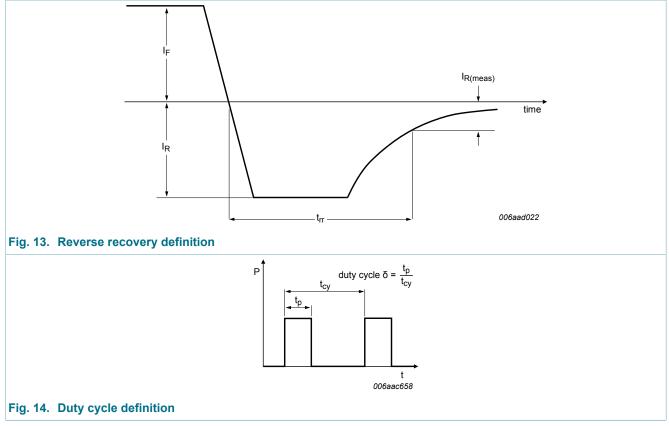
(3) δ = 0.2; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig. 11. Average forward current as a function of ambient temperature; typical values

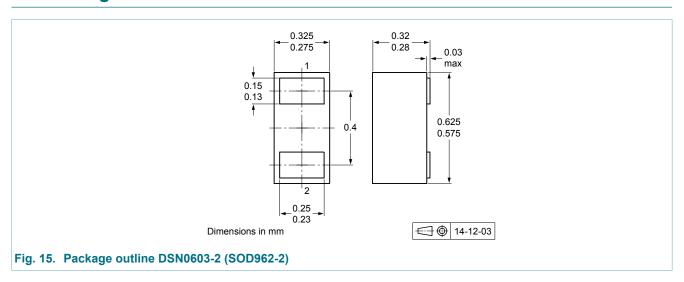


11. Test information

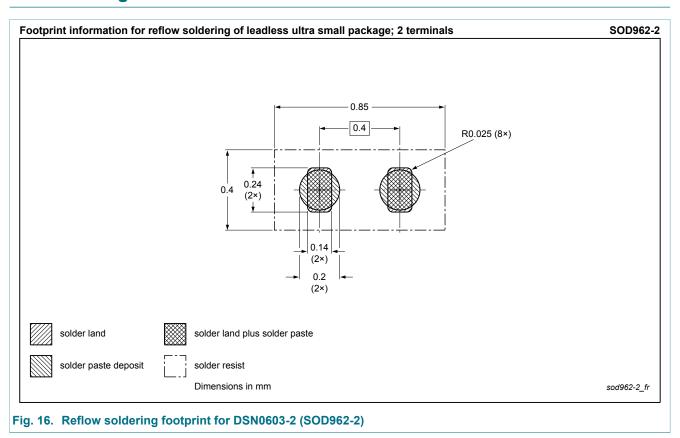


The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMEG3002AESF v.2	20150213	Product data sheet	-	PMEG3002AESF v.1		
Modifications:	Product status changed					
PMEG3002AESF v.1	20140408	Preliminary data sheet	-	-		

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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